

MIC94030/94031

TinyFET[®] P-Channel MOSFET

General Description

The MIC94030 and MIC94031 are 4-terminal silicon gate P-channel MOSFETs that provide low on-resistance in a very small package.

Designed for high-side switch applications where space is critical, the MIC94030/1 exhibits an on-resistance of typically 0.75 Ω at 4.5V gate-to-source voltage. The MIC94030/1 also operates with only 2.7V gate-to-source voltage.

The MIC94030 is the basic 4-lead P-channel MOSFET. The MIC94031 is a variation that includes an internal gate pull-up resistor that can reduce the system parts count in many applications.

The 4-terminal SOT-143 package permits a substrate connection separate from the source connection. This 4-terminal configuration improves the θ_{JA} (improved heat dissipation) and makes analog switch applications practical.

The small size, low threshold, and low $R_{DS(on)}$ make the MIC94030/1 the ideal choice for PCMCIA card sleep mode or distributed power management applications.

Features

- 13.5V minimum drain-to-source breakdown
- 0.75Ω typical on-resistance
 - at 4.5V gate-to-source voltage
- 0.45Ω typical on-resistance
 at 10V gate-to-source voltage
- Operates with 2.7V gate-to-source voltage
- Separate substrate connection for added control
- Industry's smallest surface mount package

Applications

- Distributed power management
- PCMCIA card power management
- Battery-powered computers, peripherals
- Hand-held bar-code scanners
- Portable communications equipment

Part Number			Junction Tomp Banga	Paakaga		
Standard	Marking	Pb-Free	Marking	Junction Temp. Range	rackaye	
MIC94030BM4	P30	MIC94030YM4	<u>P</u> 30	–55° to +150°C	SOT-143	
MIC94031BM4	P31	MIC94031YM4	<u>P</u> 31	–55° to +150°C	SOT-143	

Pin Configuration

Ordering Information



Typical PCB Layout



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Schematic Symbol

Functional Diagrams



Absolute Maximum Ratings⁽¹⁾

Voltage and current va	lues are negative.	e. Signs not shown for clarity.	
J			

Drain-to-Source Voltage (pulse)	16V
Gate-to-Source Voltage (pulse).	16V
Continuous Drain Current	
T _A = 25°C	1A
T _A = 100°C	0.5A
Operating Junction Temperature	–55°C to +150°C
Storage Temperature	–55°C to +150°C

Total Power Dissipation	
T _A = 25°C	568mW
$T_{A} = 100^{\circ}C$	227mW
Thermal Resistance	
θ _{JA}	220°C/W
θ _{JC}	130°C/W
Lead Temperature	
1/16" from case, 10s	+300°C

Electrical Characteristics

Symbol	Parameter	Condition (Note 1)	Min	Тур	Max	Units
V _{BDSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250 \mu A$	13.5			V
V _{GS}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.6	1.0	1.4	V
I _{GSS}	Gate-Body Leakage	V_{DS} = 0V, V_{GS} = 12V, Note 2, Note 3			1	μA
R _{GS}	Gate-Source Resistor	V _{DS} = 0V, V _{GS} = 12V, Note 2, Note 4	500	750	1000	kΩ
C _{ISS}	Input Capacitance	V _{GS} = 0V, V _{DS} = 12V		100		pF
I _{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 12V, V_{GS} = 0V			25	μA
		V_{DS} = 12V, V_{GS} = 0V, T_{J} = 125°C		0.010	250	μA
I _{D(ON)}	On-State Drain Current	V _{DS} = 10V, V _{GS} = 10V, Note 5		6.3		А
R _{DS(ON)}	Drain-Source On-State Resist	$V_{GS} = 10V, I_D = 100mA$ $V_{GS} = 4.5V, I_D = 100mA$ $V_{GS} = 2.7V, I_D = 100mA$		0.45 0.75 1.20	1.00	Ω Ω Ω
g fs	Forward Transconductance	V _{DS} = 10V, I _D = 200mA, Note 5		480		mS

Voltage and current values are negative. Signs not shown for clarity.

Notes:

1. $T_A = 25^{\circ}C$ unless noted. Substrate connected to source for all conditions.

2. ESD gate protection diode conducts during positive gate-to-source voltage excursions.

3. MIC94030 only.

4. MIC94031 only.

5. Pulse Test: Pulse Width \leq 80µsec, Duty Cycle \leq 0.5%.

Typical Characteristics











Typical Applications



Figure 1. Power Switch Application







Figure 3. Analog Switch Application

Package Information



- 2. Package surface to be mirror finish.
- 3. Die is facing up for mold & trim/form. \triangle Dimension are exclusive of mold flash
- and gate burr.
- $\underline{5}$ Dimension are exclusive of solder plating.



<u>SIDE VIEW</u>

SOT-143 (M4)

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